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View Online at https://aerobasegroup.com/nsn/5961-01-154-2513 **Inclosure Material:** Glass **Overall Length:** 0.160 inches **Terminal Length:** 0.800 inches **Overall Diameter:** 0.085 inches **Function For Which Designed:** Zener diode **End Application:** Wnimitz class cvn; oliver perry class ffg; forrestal class cv; kidd class ddg; tactical data system, an/uya-4 (v); toconderoga class cg (47); virginia class cgn (41); yellowstone class ad-41; spruance class dd (963); wasp class lhd **Mounting Method: Terminal Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 130.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 11.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Weapon system essential **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/406 government specification Shelf Life:

No

Unit Of Measure:

Demilitarization:

N/a

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